



New Technology Announcement

Widely Tunable, Semiconductor THz Laser

APPLICATIONS:

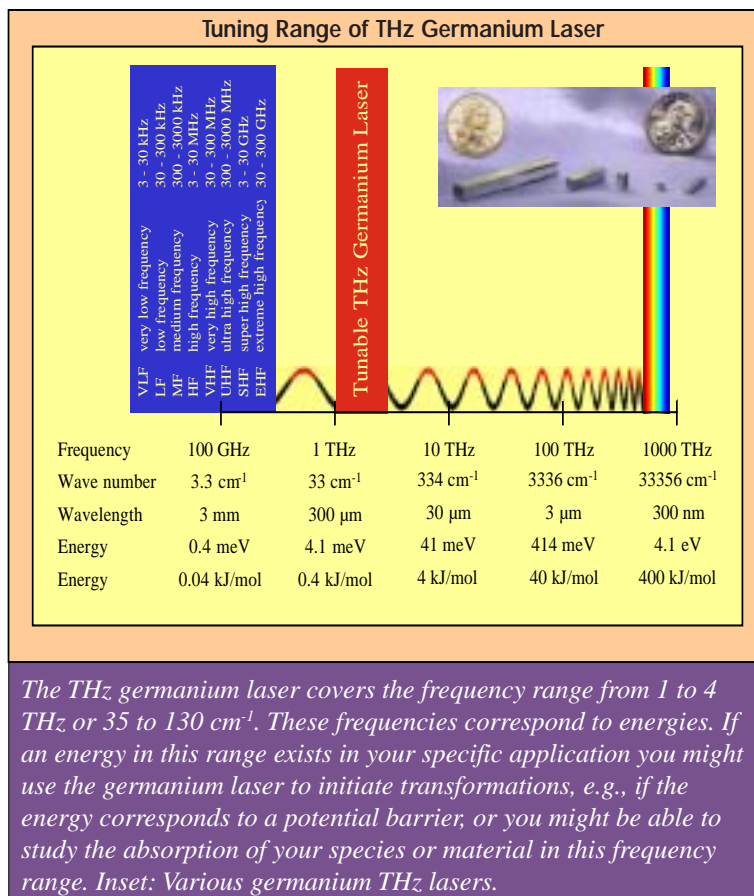
- Terahertz (THz) imaging and THz vision
- IR and far-IR optical instrumentation
- Trace gas and atmospheric monitoring
- Supramolecular chemistry
- Military applications such as radar modeling and scale-model radar THz imaging

ADVANTAGES:

- Broad tuning range 1 - 4 THz, high laser power (a few μW to several Watts), and high duty cycles up to 5%
- Electrically controlled solid state lasers provide safe, maintenance-free operation, with no need for toxic gases
- Can be operated in commercially available closed-cycle refrigerators
- All solid state

ABSTRACT:

Eugene Haller and Erik Brundermann have invented a new type of semiconductor THz and far-IR laser using lightly doped p-type germanium single crystals grown at Berkeley Lab. By changing an electric and/or magnetic field the laser can generate laser pulses or radiation tens of microseconds long with frequencies in the THz frequency range (1-4 THz, corresponding to 75-300 μm , 35-130 cm^{-1} or 4-16 meV).



The laser is operated in closed-cycle refrigerators but low temperature cryostats can be used as well. The laser is safe, maintenance-free, and electrically controlled. In contrast, commercially available THz radiation generators are large (100 ft^2), sensitive gas lasers that have emission spectra covering only a limited range of frequencies. The handling of these lasers is complex and involves using hazardous gases CH_2F_2 or HCOOH to operate them and undesirable CO_2 lasers to pump them.

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The magnetic field is applied by superconducting coils or small and inexpensive permanent magnets with a volume of about 1cm³. The maximum emission power depends on the crystal volume and can reach from a few μ W to several Watts with duty cycles of up to 5%. Current research is heading for continuous wave emission (100% duty cycle).

Berkeley's versatile, widely tunable laser source is relevant to areas that can make use of low and high resolution spectroscopy with a finesse of up to 10⁷ in the THz range such as: THz imaging and THz vision, environmental monitoring of trace gases (NO_x, CO, etc.), monitoring of the atmosphere, IR and far IR optical instrumentation, and measuring van der Waals bonding energies in biomolecules or organic semiconductors.

The high intensity THz pulses of a 0.4 cm³ laser can penetrate water layers of approximately 1 mm thickness which makes the study of biomolecules or living cells in their natural environment feasible. This is a major advantage compared to Fourier Transform spectrometers and other low intensity sources typically used in this frequency region. Military applications might be found in radar modeling and scale-model radar THz imaging.

Berkeley Lab seeks partner(s) in the development of a computer controlled laser system based on this new germanium laser. Some assistance developing prototypes could be provided.

STATUS: This technology is covered by U. S. Patent # 6,011,810. Available for collaborative research and/or licensing.

Reference Number: IB-1161

PUBLICATIONS:

- E. Bründermann, D.R. Chamberlin, and E.E. Haller, "High duty cycle and continuous terahertz emission from germanium," *Appl. Phys. Lett.* **76**, 2991-2993 (2000).
- D.R. Chamberlin, E. Bründermann, and E.E. Haller, "Planar contact geometry for far-infrared germanium lasers," *Appl. Phys. Lett.* **74**, 3761-3763 (1999).
- E. Bründermann, D.R. Chamberlin, and E.E. Haller, "Novel design concepts of widely tunable germanium terahertz lasers," *Infrared Phys. Technol.* **40**(3), 141-151 (1999).

For additional information, please visit:

http://www.mse.berkeley.edu/Groups/haller/brundermann/technology_transfer.html



Berkeley Lab seeks partners for collaborative research opportunities and licensing of this new technology

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